International Journal of Engineering, Science and Mathematics

Vol. 7 Issue 4, April 2018,

ISSN: 2320-0294 Impact Factor: 6.765

Journal Homepage: http://www.ijesm.co.in, Email: ijesmj@gmail.com

Double-Blind Peer Reviewed Refereed Open Access International Journal - Included in the International Serial Directories Indexed & Listed at: Ulrich's Periodicals Directory ©, U.S.A., Open J-Gage as well as in Cabell's Directories of Publishing Opportunities, U.S.A

Infux of Bis 2 Amino Pyridinium Maleate (B2APM) crystals

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Abstract

Bis 2 Amino Pyridinium Maleate (B2APM) crystals are NLO in nature and are grown by solution growth method, The single XRD data confirms that this crystal is having a as 21.760 Å, b as 23.555 Å, c as 5.626 Å, $\alpha = \beta = \gamma = 90^{\circ}$ and the crystal is orthorhombic in nature, Fdd2 is the space group of Bis 2 Amino Pyridinium Maleate crystals. Structure is the combination of $2C_5H_7N_2^+$. $C_4H_2O_4^-$. The refreactive influx of B2APm is be 2.5864 microns

Key Words: B2APM, XRD, INFLUX ...

Experimental

The B2APM was prepared by suspend 2-aminopyridine and maleic acid in 2:1 molar ratio in water at 100°C. Crystals of B2APM were acquired by slow evaporation of the solvent at the room temperature.

The reaction mechanism is

$$2C_5H_6N_2 + C_4H_4O_4 \rightarrow 2C_5H_7N_2^+.C_4H_2O_4^{-2}$$

Influx

Activating the inactive medium is by QEO effect and here the influx is 2.5864 microns for B2APM crystals.

Conclusion

B2APM crystals are grown by slow evaporation method and here the grown material is subjected to XRD and INFLUX and from that it is orthorhombic in nature. The single XRD data confirms that this crystal is having a as 21.760 Å, b as 23.555 Å, c as 5.626 Å, $\alpha = \beta = \gamma = 90^{\circ}$, the influx for the titled specimen be 2.5864 microns

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